

Docket No.: V0195.0008  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Franz Hofmann et al.

Application No.: 10/768,971

Confirmation No.: 4544

Filed: January 30, 2004

Art Unit: 2815

For: Fin field-effect transistor and method for  
producing a fin field effect-transistor

Examiner: E. J. Wojciechowicz

*Enter  
Remarks  
EJ*

**AMENDMENT AFTER FINAL ACTION UNDER 37 C.F.R. 1.116**

MS AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

In response to the Office Action dated March 23, 2006, the following Remarks are respectfully submitted.

Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 8 of this paper.